

TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

SM10LZ47

AC POWER CONTROL APPLICATIONS

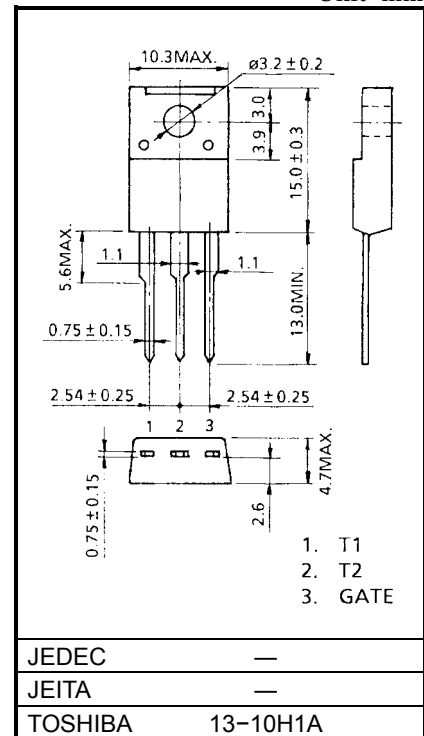
- Repetitive Peak Off-State Voltage : $V_{DRM} = 800V$
- R.M.S. On-State Current : $I_T (RMS) = 10A$
- High Commutation (dv / dt)
- Isolation Voltage : $V_{ISOL} = 1500V AC$

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Repetitive Peak Off-State Voltage	V_{DRM}	800	V
R.M.S. On-State Current (Full Sine Waveform)	$I_T (RMS)$	10	A
Peak One Cycle Surge On-State Current (Non-Repetitive)	I_{TSM}	100 (50Hz) 110 (60Hz)	A
I^2t Limit Value	I^2t	50	A^2s
Critical Rate of Rise of On-State Current (Note)	di / dt	50	A / μs
Peak Gate Power Dissipation	P_{GM}	5	W
Average Gate Power Dissipation	$P_G (AV)$	0.5	W
Peak Gate Voltage	V_{FGM}	10	V
Peak Gate Current	I_{GM}	2	A
Junction Temperature	T_j	-40~125	°C
Storage Temperature Range	T_{stg}	-40~125	°C
Isolation Voltage (AC, t = 1min.)	V_{ISOL}	1500	V

Note: di / dt test condition
 $V_{DRM} = 0.5 \times \text{Rated}$, $I_{TM} \leq 15A$, $t_{gw} \geq 10\mu s$,
 $t_{gr} \leq 250ns$, $i_{gp} = I_{GT} \times 2.0$

Unit: mm

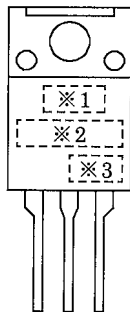


Weight: 1.7g

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current	I_{DRM}	$V_{DRM} = \text{Rated}$	—	—	20	μA
Gate Trigger Voltage	I	$V_D = 12\text{V}$, $R_L = 20\Omega$	—	—	1.5	V
	II				1.5	
	III				1.5	
Gate Trigger Current	I	$V_D = 12\text{V}$, $R_L = 20\Omega$	—	—	30	mA
	II				30	
	III				30	
Peak On-State Voltage	V_{TM}	$I_{TM} = 15\text{A}$	—	—	1.5	V
Gate Non-Trigger Voltage	V_{GD}	$V_D = \text{Rated}$, $T_c = 125^\circ\text{C}$	0.2	—	—	V
Holding Current	I_H	$V_D = 12\text{V}$, $I_{TM} = 1\text{A}$	—	—	50	mA
Thermal Resistance	$R_{th(j-c)}$	Junction to Case, AC	—	—	3.4	$^\circ\text{C} / \text{W}$
Critical Rate of Rise of Off-State Voltage	dv / dt	$V_{DRM} = 600\text{V}$, $T_j = 125^\circ\text{C}$ Exponential Rise	—	300	—	$\text{V} / \mu\text{s}$
Critical Rate of Rise of Off-State Voltage at Commutation	$(dv / dt)_c$	$V_{DRM} = 400\text{V}$, $T_j = 125^\circ\text{C}$ $(di / dt)_c = -5.5\text{A} / \text{ms}$	10	—	—	$\text{V} / \mu\text{s}$

MARKING



NUMBER	SYMBOL	MARK
*1	TOSHIBA PRODUCT MARK	
*2	TYPE	SM10LZ47
*3	Lot Number <div style="display: flex; align-items: center;"> <div style="border: 1px solid black; width: 15px; height: 15px; margin-right: 5px;"></div> <div style="margin-right: 5px;">Month (Starting from Alphabet A)</div> </div> <div style="display: flex; align-items: center;"> <div style="border: 1px solid black; width: 15px; height: 15px; margin-right: 5px;"></div> <div>Year (Last Decimal Digit of the Current Year)</div> </div>	Example 8A: January 1998 8B: February 1998 8L: December 1998

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